

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## D5SB10 THRU D5SB80

SINGLE PHASE GLASS
PASSIVATED SIP BRIDGE RECTIFIER
VOLTAGE: 100 TO 800V CURRENT: 6.0A

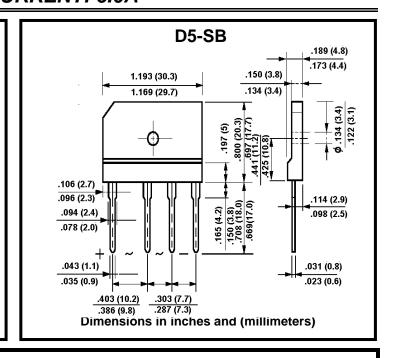
TECHNICAL SPECIFICATION

### **FEATURES**

- Glass passivated junction chip
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- Surge overload rating: 150 A peak
- High temperature soldering guaranteed: 250°C/10sec/ 0.575" (9.5mm) lead length at 5 lbs tension

#### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Polarity symbol marked on body
- Mounting position: Any



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	D5SB 10	D5SB 20	D5SB 40	D5SB 60	D5SB 80	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	200	400	600	800	V
Maximum RMS Voltage	$V_{RMS}$	70	140	280	420	560	V
Maximum DC Blocking Voltage	$V_{DC}$	100	200	400	600	800	V
Maximum Average Forward Rectified Current (T <sub>a</sub> =50°C)	I <sub>F(AV)</sub>	6.0					Α
Peak Forward Surge Current (8.5ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	150					Α
Maximum Instantaneous Forward Voltage (at forward current 3.0A DC)	$V_{F}$	1.1					V
Maximum DC Reverse Current $T_a=25^{\circ}$ C (at rated DC blocking voltage) $T_a=125^{\circ}$ C		5 500					μA μA
Storage and Operating Junction Temperature	$T_{STG},T_{J}$	-55 to + 150					°C

http://www.sse-diode.com